

Publications of George Dimitrakopoulos

Chapters in collective volumes

Interfacial and junction line defect analysis for plasticity investigations

in J. Lépinoux, D. Mazière, V. Pontikis, and G. Saada (eds.) "Multiscale Phenomena in Plasticity : from experiments to phenomenology, modeling and materials engineering" NATO Science Series (Kluwer Academic Publishers) **367**, 205-214 (2000)

Th. Karakostas, G. P. Dimitrakopoulos, J.G. Antonopoulos, and R. C. Pond

Topological analysis of defects in nitride semiconductors

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G. P. Dimitrakopoulos, Ph. Komninou, Th. Karakostas, and R. C. Pond

Interfaces and defect interactions in nitride compound semiconductors for optoelectronic applications

Chapter 27 in *Recent Research Developments in Physics* vol.4 (2003), pp. 593-629 (Transworld Research Network, India, 2004, ISBN: 81-7895-078-2)

Ph. Komninou, G. P. Dimitrakopoulos, Th. Kehagias, J. Kioseoglou, and Th. Karakostas

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